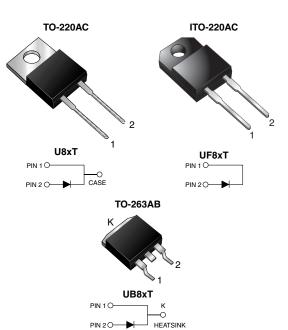
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PRIMARY CHARACTERISTICS					
I _{F(AV)}	8.0 A				
V _{RRM}	100 V to 200 V				
I _{FSM}	100 A				
t _{rr}	20 ns				
V _F at I _F = 8 A	0.79 V				
T _J max.	150 °C				
Package	TO-220AC, ITO-220AC, TO-263AB				
Diode variations	Single die				

Ultrafast Rectifier

FEATURES

- Power pack
- · Oxide planar chip junction
- · Ultrafast recovery time
- · Low switching losses, high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max., 10 s per JESD 22-B106 (for TO-220AC and ITO-220AC package)
- AEC-Q101 gualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer computer, automotive and telecommunication applications.

MECHANICAL DATA

Case: TO-220AC, ITO-220AC, TO-263AB

Molding compound meets UL 94V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS ($T_C = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	U8BT	U8CT	U8DT	UNIT	
Max. repetitive peak reverse voltage	V _{RRM}	100	150	200	V	
Max. average forward rectified current (Fig. 1)	V _{F(AV)}	8.0			V	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	100			А	
Isolation voltage (ITO-220AC only) from terminals to heatsink t = 1 min	V _{AC}	1500			V	
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150			°C	

RoHS

COMPLIANT



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ELECTRICAL CHARACTERISTICS ($T_c = 25 \ ^{\circ}C$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage ⁽¹⁾	I _F = 5 A	T _A = 25 °C	- V _F	0.90	-	
	I _F = 8 A			0.96	1.02	
	I _F = 20 A			1.12	-	V
	I _F = 5 A	T _A = 150 °C		0.72	-	
	I _F = 8 A			0.79	0.86	
	I _F = 20 A			0.99	-	
Reverse current ⁽²⁾	Rated V _R $\frac{T_A = 25 \text{ °C}}{T_A = 100 \text{ °C}}$		-	10		
		T _A = 100 °C	I _R	200	500	μΑ
Reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	15	20	ns
Reverse recovery time	I_F = 1.0 A, dI/dt = 100 A/µs, V_R = 30 V, I_{rr} = 0.1 I_{RM}		t _{rr}	19	-	ns
Storage charge			Q _{rr}	7.1	-	nC
Reverse recovery time	I_F = 8 A, dI/dt = 50 A/µs, V_R = 30 V, I_{rr} = 0.1 I_{RM}		t _{rr}	23	-	ns
Storage charge			Q _{rr}	6.5	-	nC
Typical junction capacitance	4.0 V, 1 MHz		CJ	25	-	pF

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_c = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	U8xT	UF8xT	UB8xT	UNIT	
Typical thermal resistance from junction to case	$R_{\theta JC}$	4.0	5.0	4.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AC	U8DT-E3/4W	1.83	4W	50/tube	Tube		
ITO-220AC	UF8DT-E3/4W	1.69	4W	50/tube	Tube		
TO-263AB	UB8DT-E3/4W	1.37	4W	50/tube	Tube		
TO-263AB	UB8DT-E3/8W	1.37	8W	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

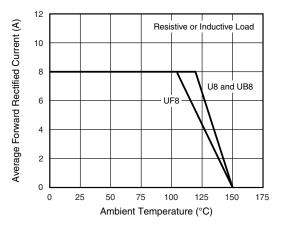


Fig. 1 - Max. Forward Current Derating Curve

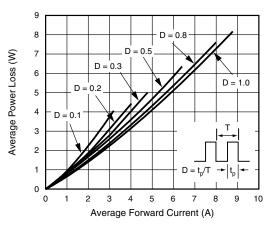


Fig. 2 - Forward Power Loss Characteristics

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2

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Fig. 4 - Typical Reverse Leakage Charateristics

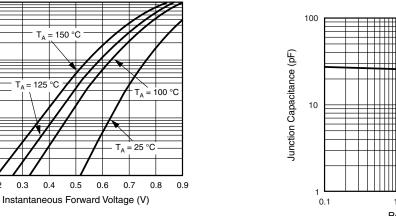
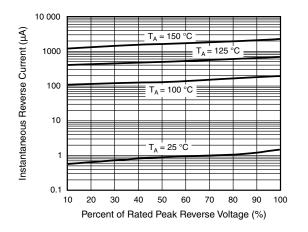


Fig. 3 - Typical Instantaneous Forward Charateristics

0.6



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T_A = 150 °C

= 125 °C

> 0.4 0.5

10

1

0.1

0.01 0.1

0.2 0.3

Instantaneous Forward Current (A)

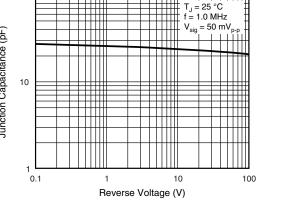
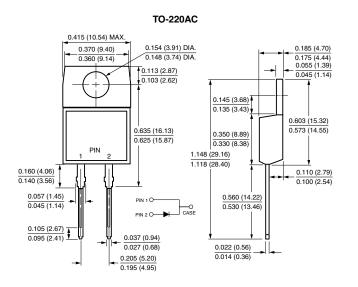
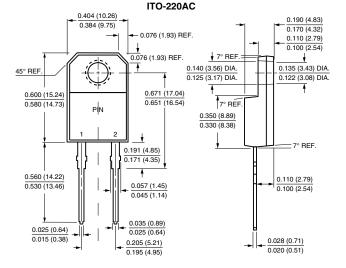


Fig. 5 - Typical Junction Capacitance

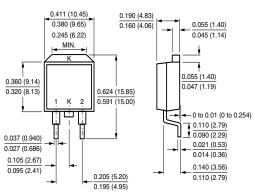
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

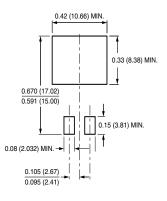




TO-263AB



Mounting Pad Layout





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